

●Application

- Motor drive
- Converter
- Photovoltaics, wind power generation.

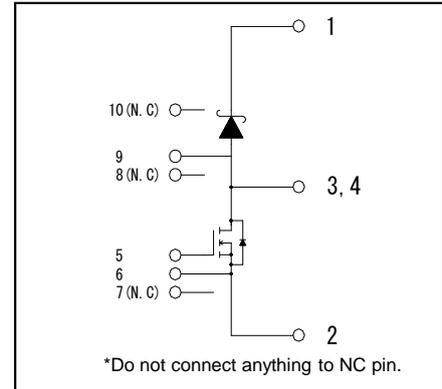
●Features

- 1) Low surge, low switching loss.
- 2) High-speed switching possible.
- 3) Reduced temperature dependence.

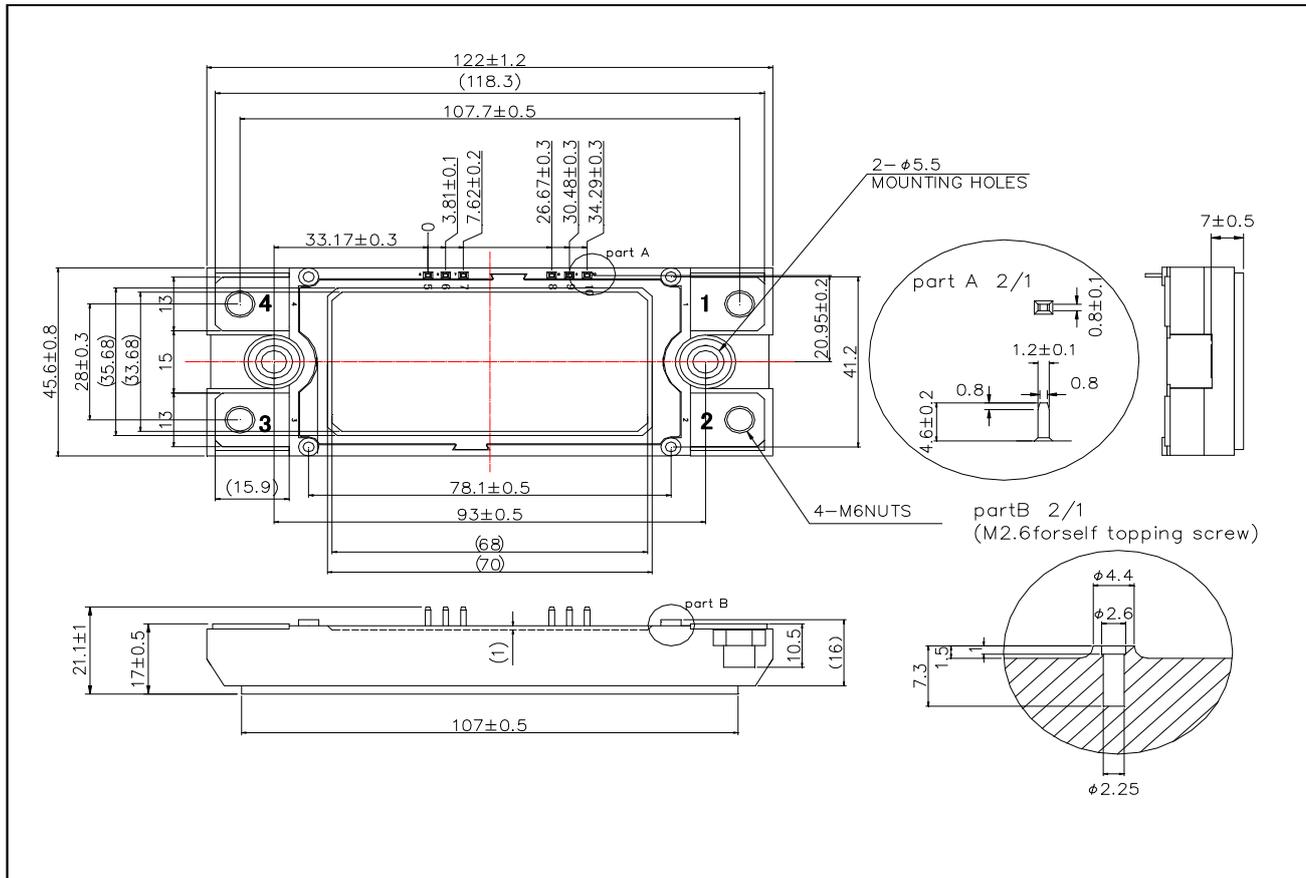
●Construction

This product is a chopper module consisting of SiC-DMOSFET and SiC-SBD from ROHM.

●Circuit diagram



●Dimensions & Pin layout (Unit : mm)



● Absolute maximum ratings ($T_j = 25^\circ\text{C}$)

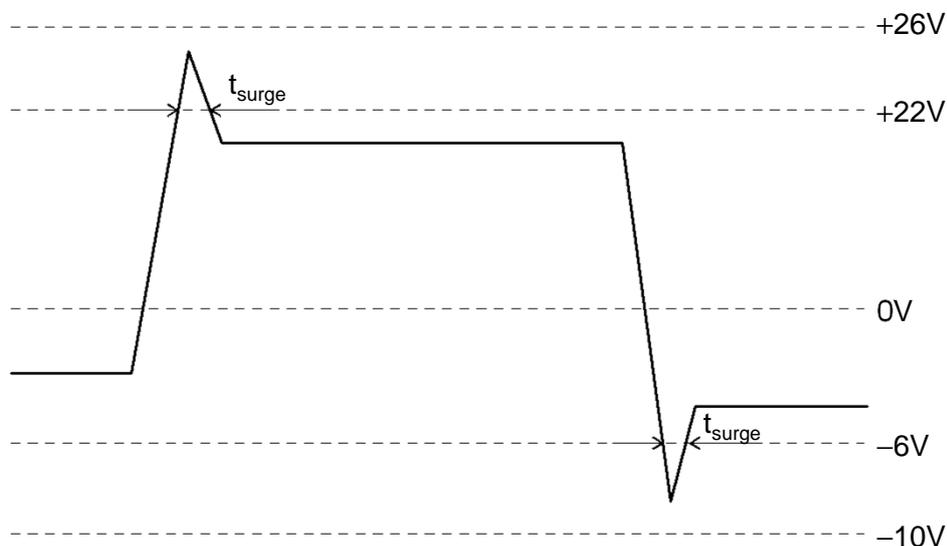
Parameter	Symbol	Conditions	Limit	Unit
Drain-source voltage	V_{DSS}	G-S short	1200	V
Repetitive reverse voltage	V_{DSS}	Clamp diode	1200	
Gate-source voltage(+)	V_{GSS}	D-S short	22	
Gate-source voltage(-)			-6	
G - S Voltage ($t_{surge} < 300\text{ns}$)	V_{GSS_surge}	D-S short	-10 to 26	
Drain current *1	I_D	DC ($T_c=60^\circ\text{C}$)	134	A
	I_{DRM}	Pulse ($T_c=60^\circ\text{C}$) 1ms *2	240	
	I_{DRM}	Pulse ($T_c=60^\circ\text{C}$) 10us *2	360	
Source current *1	I_S	DC ($T_c=60^\circ\text{C}$) $V_{GS}=18\text{V}$	134	
	I_{SRM}	Pulse ($T_c=60^\circ\text{C}$) 1ms $V_{GS}=18\text{V}$ *2	240	
	I_{SRM}	Pulse ($T_c=60^\circ\text{C}$) 10us $V_{GS}=18\text{V}$ *2	360	
Forward current (clamp diode) *1	I_F	DC ($T_c=60^\circ\text{C}$) $V_{GS}=18\text{V}$	134	
	I_{FRM}	Pulse ($T_c=60^\circ\text{C}$) 1ms $V_{GS}=18\text{V}$ *2	240	
	I_{FRM}	Pulse ($T_c=60^\circ\text{C}$) 10us $V_{GS}=18\text{V}$ *2	360	
Total power dissipation *4	P_{tot}	$T_c=25^\circ\text{C}$	935	W
Max Junction Temperature	T_{jmax}		175	$^\circ\text{C}$
Junction temperature	T_{jop}		-40 to 150	
Storage temperature	T_{stg}		-40 to 125	
Isolation voltage	Visol	Terminals to baseplate, $f=60\text{Hz}$ AC 1min.	2500	Vrms
Mounting torque	-	Main Terminals : M6 screw	4.5	N · m
		Mounting to heat sink : M5 screw	3.5	

(*1) Case temperature (T_c) is defined on the surface of base plate just under the chips.

(*2) Repetition rate should be kept within the range where temperature rise if die should not exceed T_{jmax} .

(*3) T_j is less than 175°C

Example of acceptable V_{GS} waveform



●Electrical characteristics (T_j=25°C)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
On-state static Drain-Source Voltage	V _{DS(on)}	I _D 120A, V _{GS} =18V	T _j =25°C	-	2.1	3.2	V
			T _j =125°C	-	3.1	-	
			T _j =150°C	-	3.4	5.2	
Drain cutoff current	I _{DSS}	V _{DS} =1200V, V _{GS} =0V	-	-	10	μA	
Forward Voltage	V _F	I _F =120A	T _j =25°C	-	1.7	2.1	V
			T _j =125°C	-	2.2	-	
			T _j =150°C	-	2.4	3.2	
Reverse current	I _{RRM}	Clamp diode	-	-	2	mA	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =10V, I _D =22mA	1.6	-	4	V	
Gate-source leakage current	I _{GSS}	V _{GS} =22V, V _{DS} =0V	-	-	0.5	μA	
		V _{GS} = -6V, V _{DS} =0V	-0.5	-	-		
Switching characteristics	t _{d(on)}	V _{GS(on)} =18V, V _{GS(off)} =0V	-	30	-	ns	
	t _r	V _{DS} =600V	-	40	-		
	t _{rr}	I _D =120A	-	20	-		
	t _{d(off)}	R _G =2.2Ω	-	165	-		
	t _f	inductive load	-	45	-		
Input capacitance	C _{iss}	V _{DS} =10V, V _{GS} =0V, 1MHz	-	14	-	nF	
Gate Registance	R _{Gint}	T _j =25°C	-	1.8	-	Ω	
Stray Inductance	L _s			25	-	nH	
Creepage Distance	-	Terminal to heat sink		12.5	-	mm	
		Terminal to terminal		20	-	mm	
Clearance Distance	-	Terminal to heat sink		10.5	-	mm	
		Terminal to terminal		14	-	mm	
Junction-to-case thermal resistance	R _{th(j-c)}	DMOS (1/2 module) *4	-	-	0.16	°C/W	
		SBD (1/2 module) *4	-	-	0.21		
Case-to-heat sink Thermal resistance	R _{th(c-f)}	Case to heat sink, per 1 module, Thermal grease applied *5	-	0.035	-		

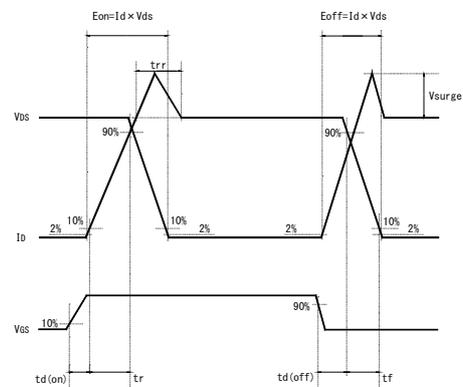
(*4) Measurement of T_c is to be done at the point just under the chip.

(*5) Typical value is measured by using thermally conductive grease of λ=0.9W/(m · K).

(*6) SiC devices have lower short circuit withstand capability due to high current density. Please be advised to pay careful attention to short circuit accident and try to adjust protection time to shutdown them as short as possible.

(*7) If the Product is used beyond absolute maximum ratings defined in the Specifications, as its internal structure may be damaged, please replace such Product with a new one.

<Wavelength for Switching Test>



●Electrical characteristic curves (Typical)

Fig.1 Typical Output Characteristics [$T_j=25^\circ\text{C}$]

Fig.2 Drain-Source Voltage vs. Drain Current

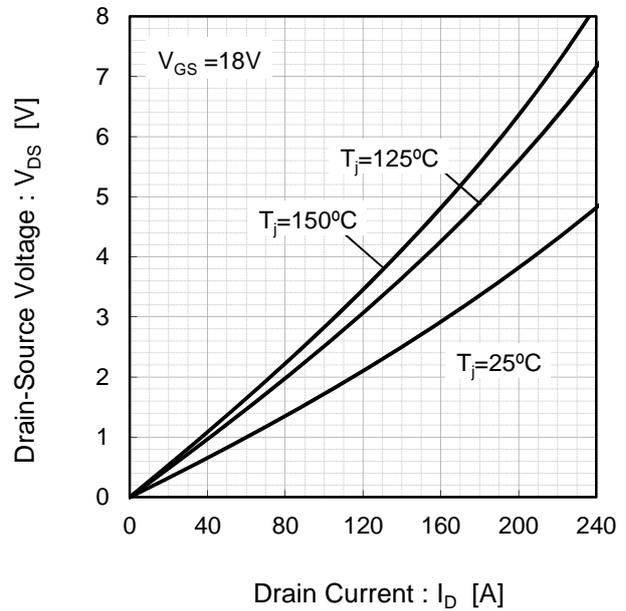
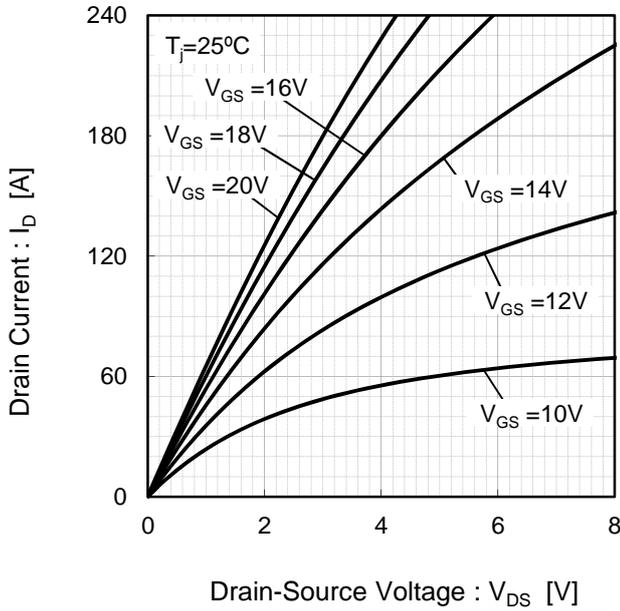
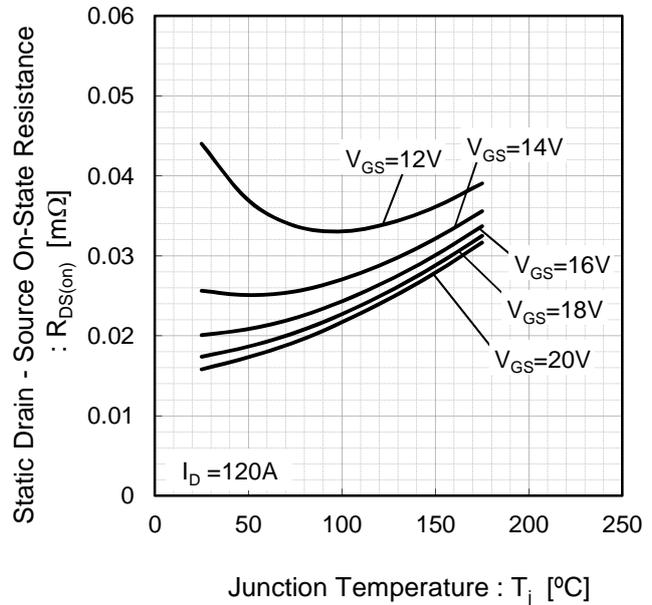
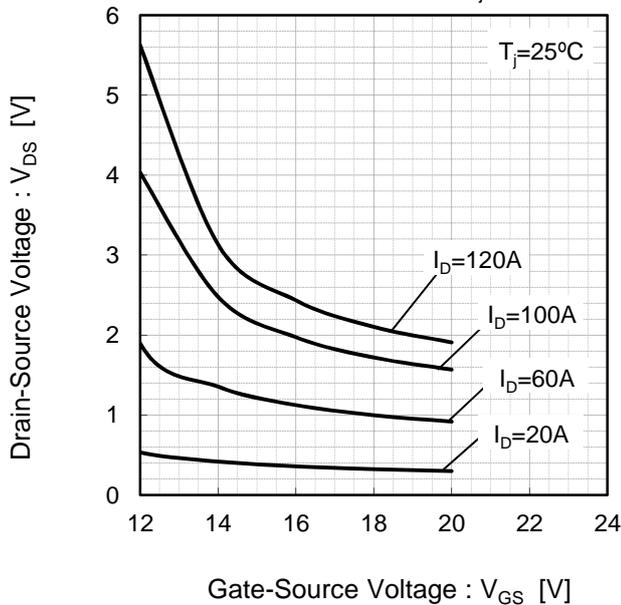


Fig.3 Drain-Source Voltage vs. Gate-Source Voltage [$T_j=25^\circ\text{C}$]

Fig.4 Static Drain - Source On-State Resistance vs. Junction Temperature



●Electrical characteristic curves (Typical)

Fig.5 Forward characteristic of Diode

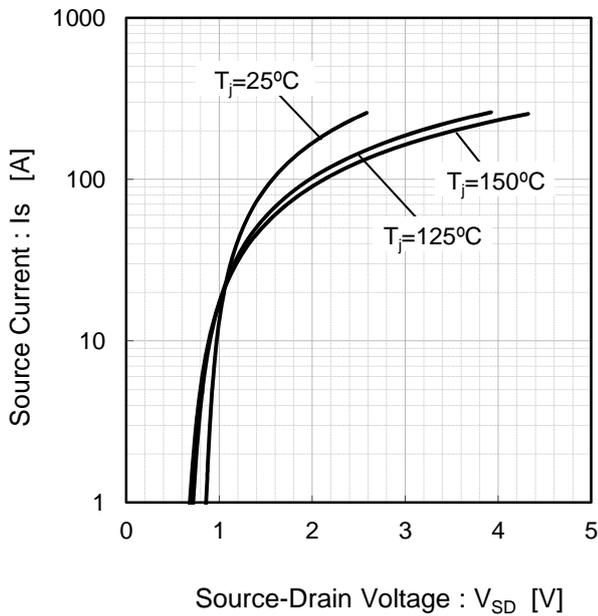


Fig.6 Forward characteristic of Diode

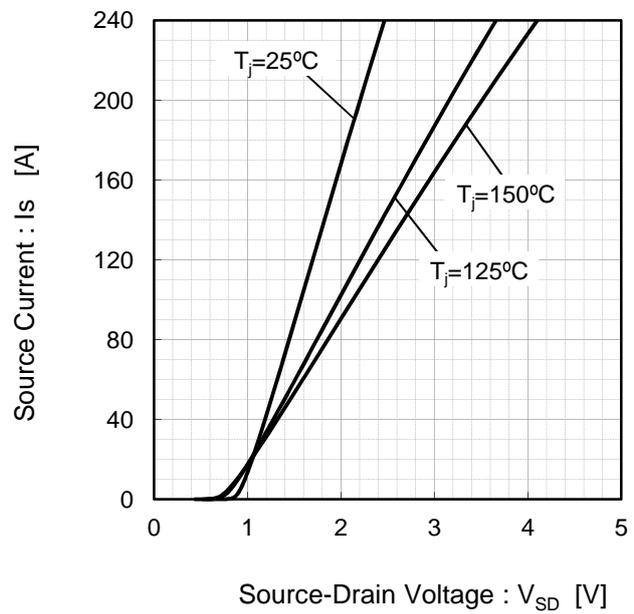


Fig.7 Drain Current vs. Gate-Source Voltage

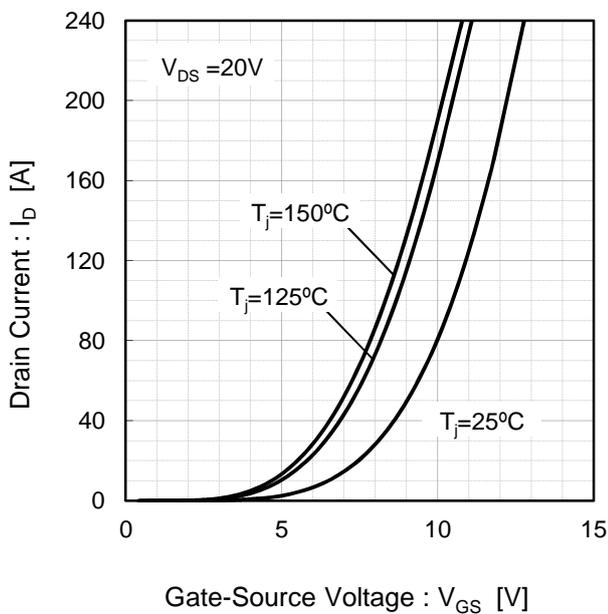
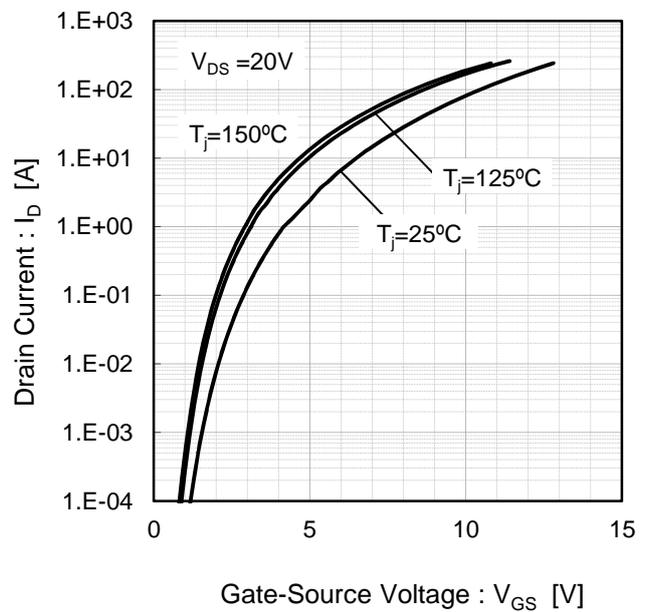


Fig.8 Drain Current vs. Gate-Source Voltage



●Electrical characteristic curves (Typical)

Fig.9 Switching Characteristics [$T_j=25^{\circ}\text{C}$]

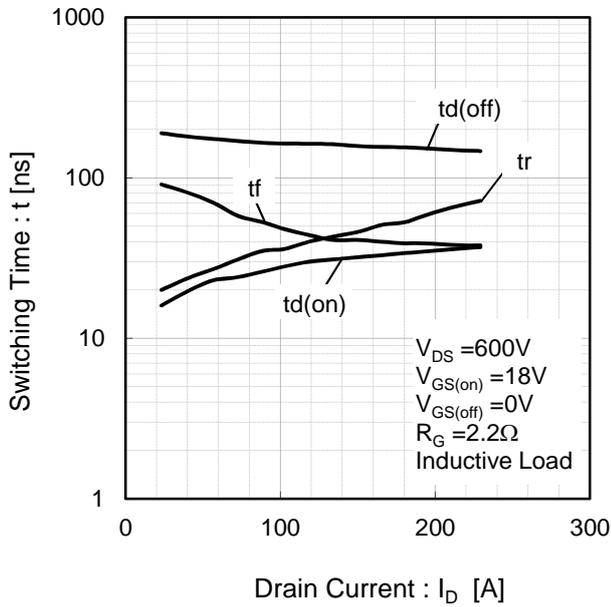


Fig.10 Switching Characteristics [$T_j=125^{\circ}\text{C}$]

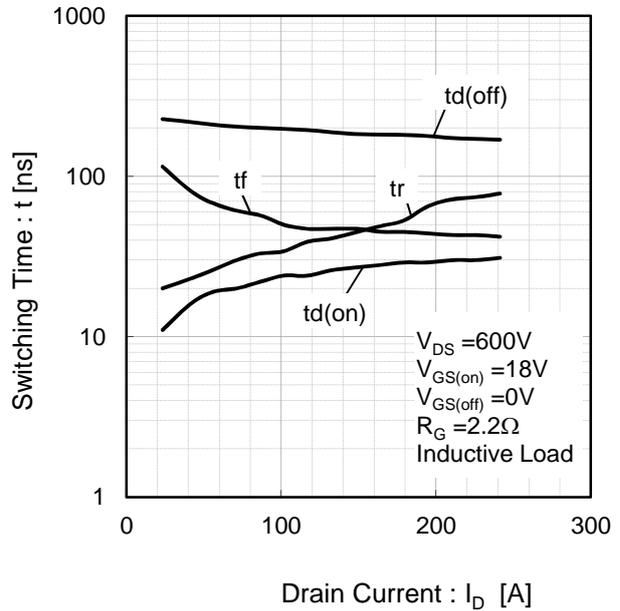


Fig.11 Switching Characteristics [$T_j=150^{\circ}\text{C}$]

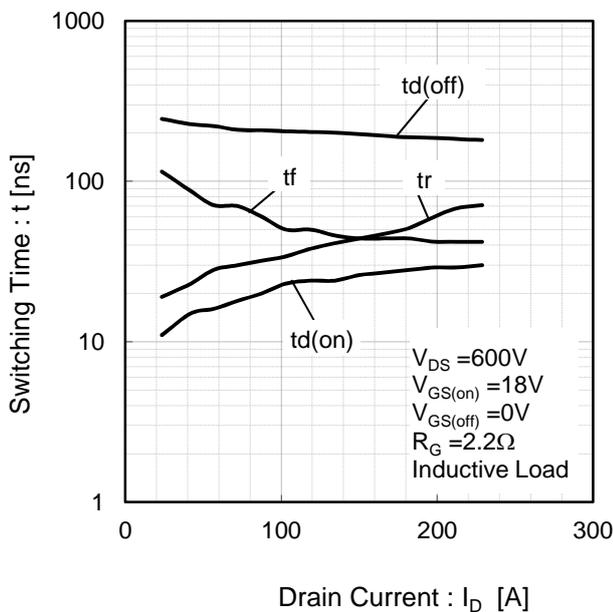
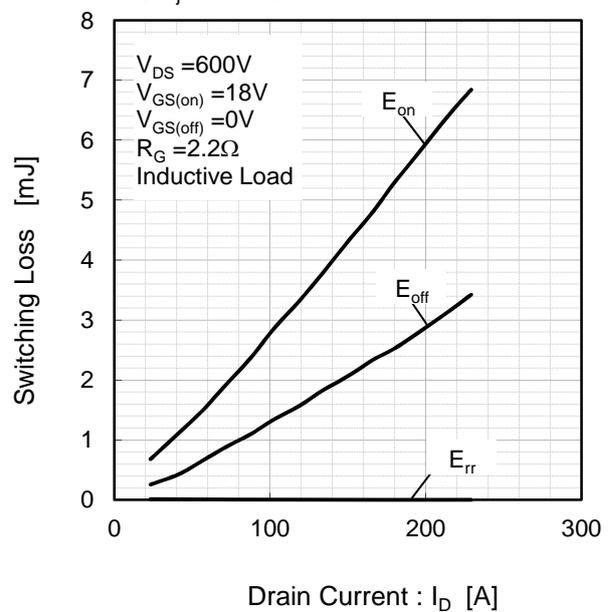


Fig.12 Switching Loss vs. Drain Current [$T_j=25^{\circ}\text{C}$]



●Electrical characteristic curves (Typical)

Fig.13 Switching Loss vs. Drain Current [$T_j=125^\circ\text{C}$]

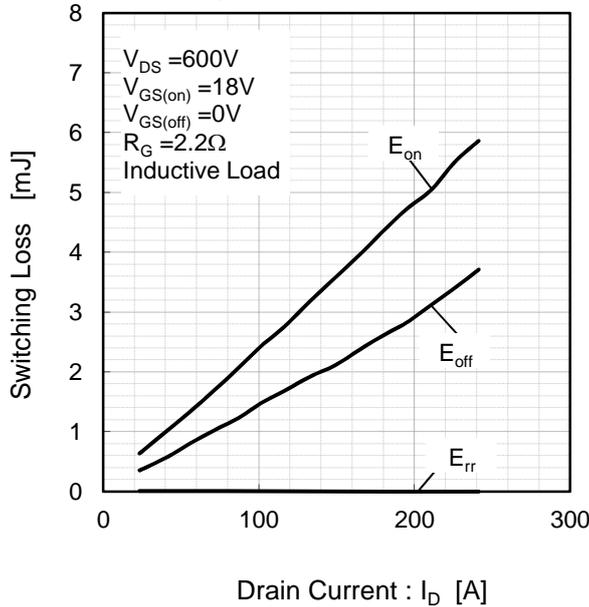


Fig.14 Switching Loss vs. Drain Current [$T_j=150^\circ\text{C}$]

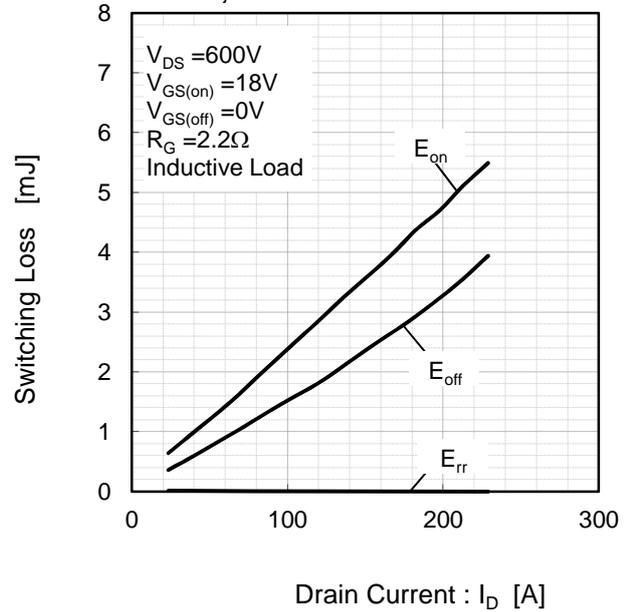


Fig.15 Recovery Characteristics vs. Drain Current [$T_j=25^\circ\text{C}$]

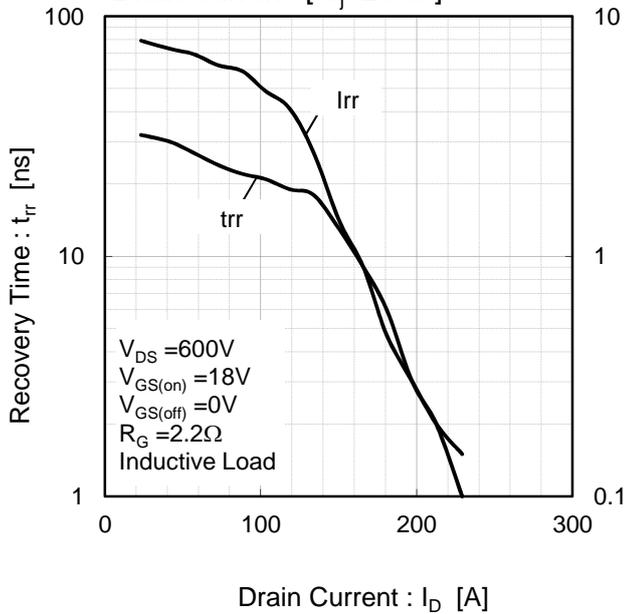
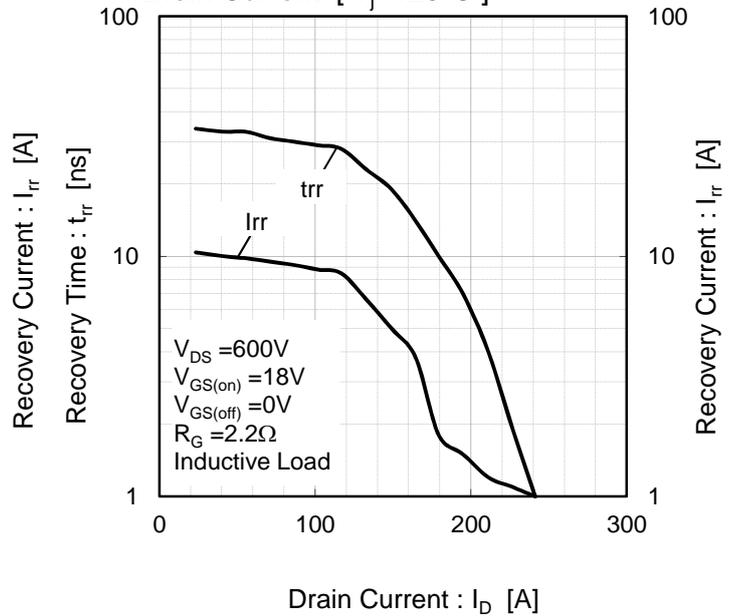


Fig.16 Recovery Characteristics vs. Drain Current [$T_j=125^\circ\text{C}$]



●Electrical characteristic curves (Typical)

Fig.17 Recovery Characteristics vs. Drain Current [$T_j=150^\circ\text{C}$]

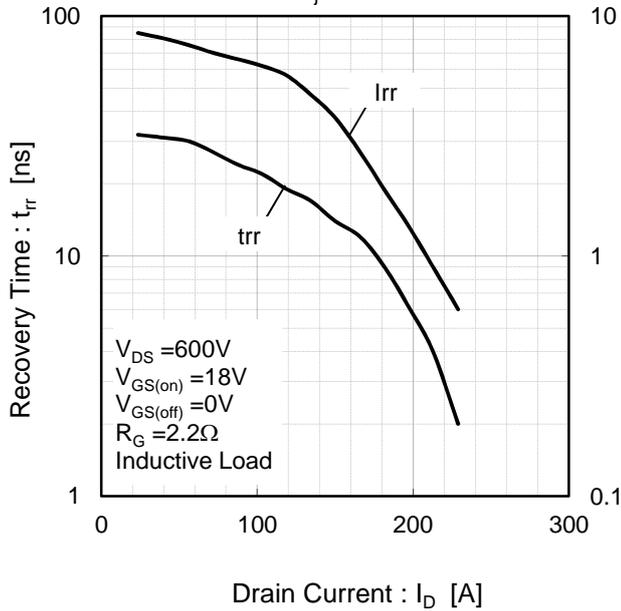


Fig.18 Switching Characteristics vs. Gate Resistance [$T_j=25^\circ\text{C}$]

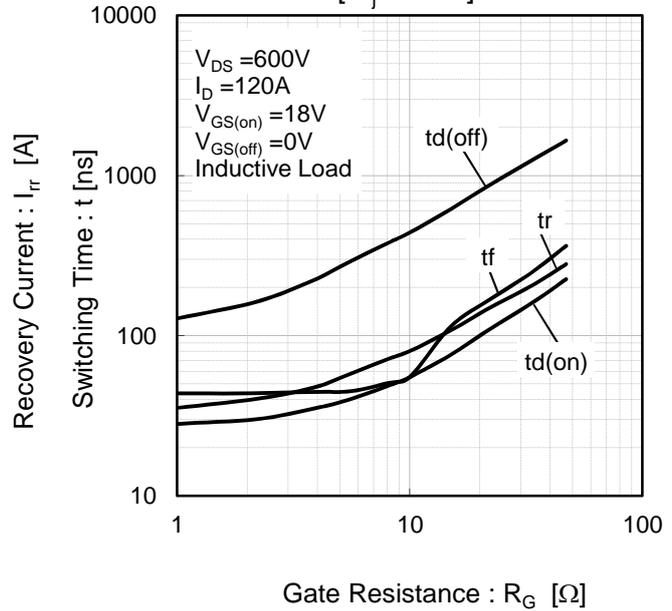


Fig.19 Switching Characteristics vs. Gate Resistance [$T_j=125^\circ\text{C}$]

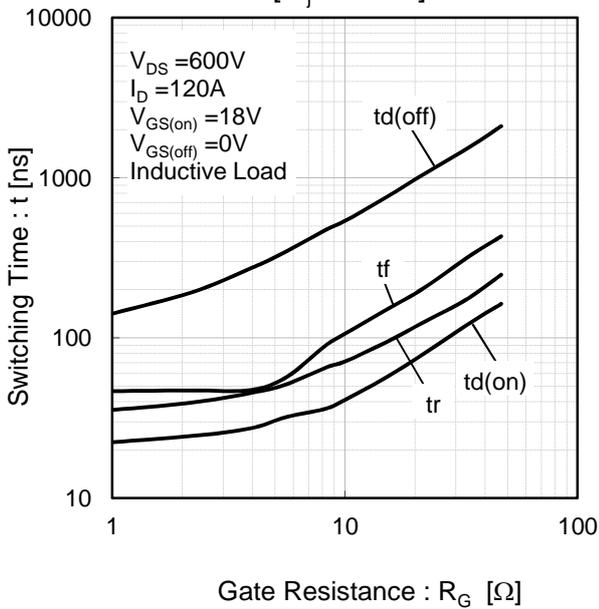
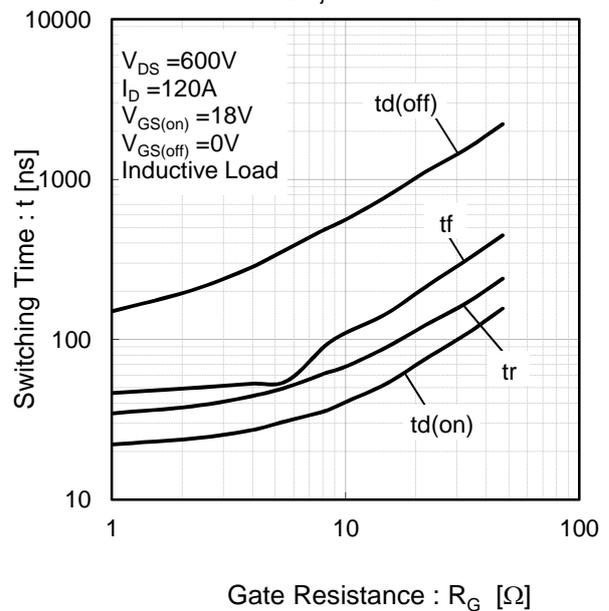


Fig.20 Switching Characteristics vs. Gate Resistance [$T_j=150^\circ\text{C}$]



●Electrical characteristic curves (Typical)

Fig.21 Switching Loss vs. Gate Resistance [$T_j=25^{\circ}\text{C}$]

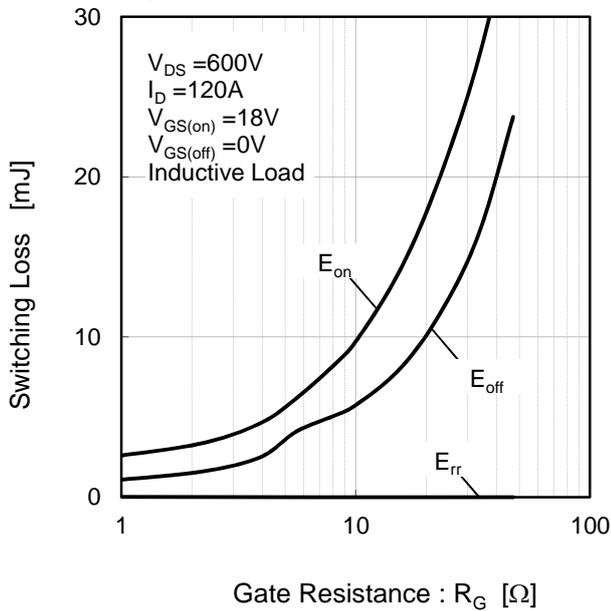


Fig.22 Switching Loss vs. Gate Resistance [$T_j=125^{\circ}\text{C}$]

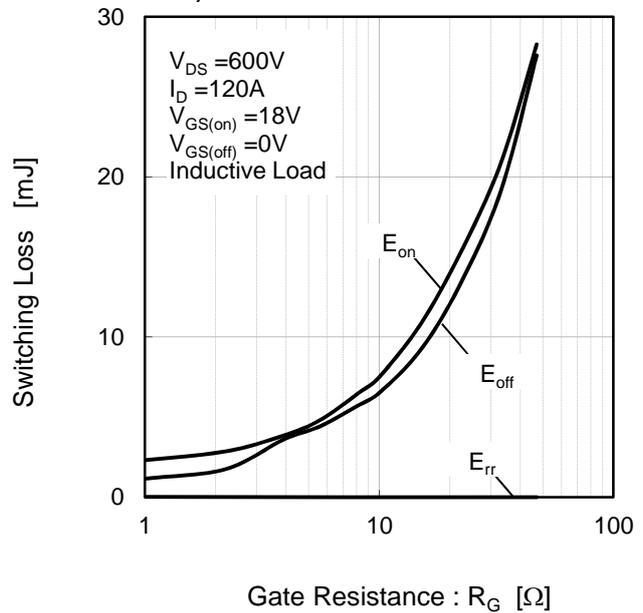


Fig.23 Switching Loss vs. Gate Resistance [$T_j=150^{\circ}\text{C}$]

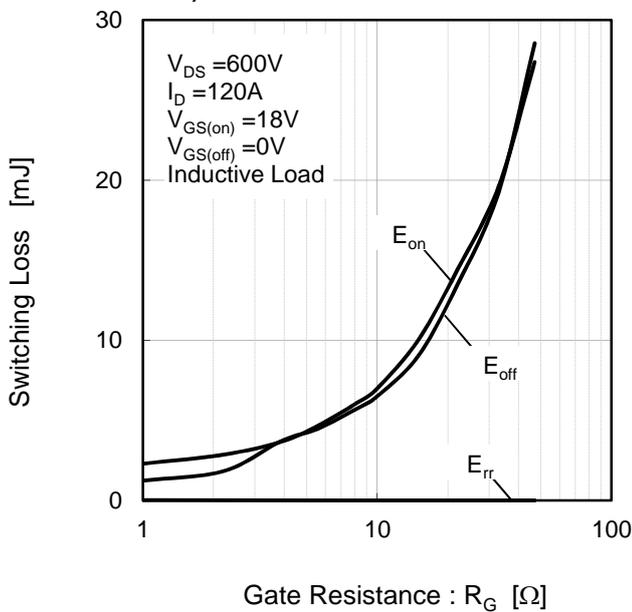
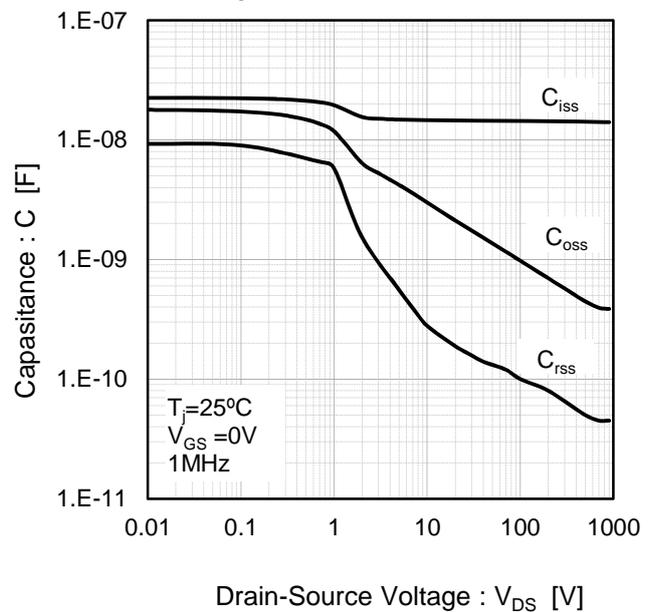


Fig.24 Typical Capacitance vs. Drain-Source Voltage



●Electrical characteristic curves (Typical)

Fig.25 Gate Charge Characteristics
[$T_j=25^\circ\text{C}$]

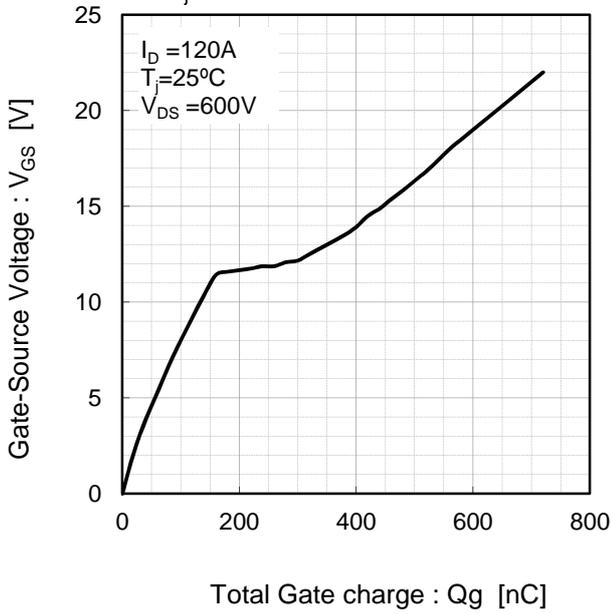
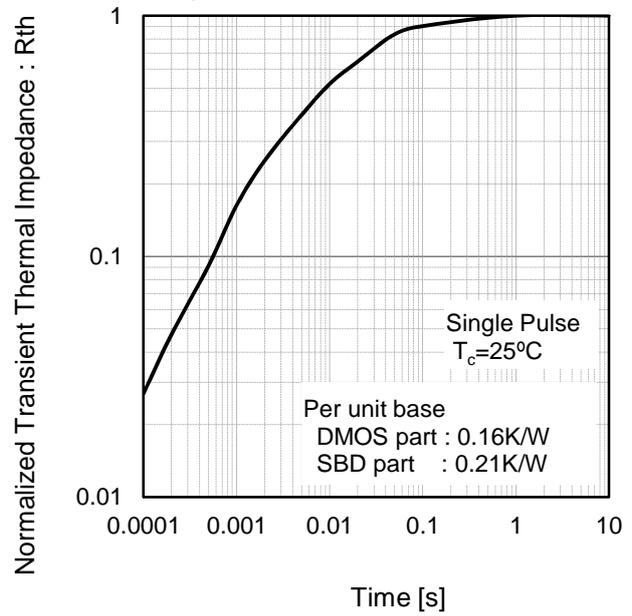


Fig.26 Normalized Transient Thermal Impedance



Notes

- 1) The information contained herein is subject to change without notice.
- 2) Before you use our Products, please contact our sales representative and verify the latest specifications.
- 3) Although ROHM is continuously working to improve product reliability and quality, semiconductors can break down and malfunction due to various factors. Therefore, in order to prevent personal injury or fire arising from failure, please take safety measures such as complying with the derating characteristics, implementing redundant and fire prevention designs, and utilizing backups and fail-safe procedures. ROHM shall have no responsibility for any damages arising out of the use of our Products beyond the rating specified by ROHM.
- 4) Examples of application circuits, circuit constants and any other information contained herein are provided only to illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.
- 5) The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM or any other parties. ROHM shall have no responsibility whatsoever for any dispute arising out of the use of such technical information.
- 6) The Products specified in this document are not designed to be radiation tolerant.
- 7) For use of our Products in applications requiring a high degree of reliability (as exemplified below), please contact and consult with a ROHM representative : transportation equipment (i.e. cars, ships, trains), primary communication equipment, traffic lights, fire/crime prevention, safety equipment, medical systems, and power transmission systems.
- 8) Do not use our Products in applications requiring extremely high reliability, such as aerospace equipment, nuclear power control systems, and submarine repeaters.
- 9) ROHM shall have no responsibility for any damages or injury arising from non-compliance with the recommended usage conditions and specifications contained herein.
- 10) ROHM has used reasonable care to ensure the accuracy of the information contained in this document. However, ROHM does not warrants that such information is error-free, and ROHM shall have no responsibility for any damages arising from any inaccuracy or misprint of such information.
- 11) Please use the Products in accordance with any applicable environmental laws and regulations, such as the RoHS Directive. For more details, including RoHS compatibility, please contact a ROHM sales office. ROHM shall have no responsibility for any damages or losses resulting non-compliance with any applicable laws or regulations.
- 12) When providing our Products and technologies contained in this document to other countries, you must abide by the procedures and provisions stipulated in all applicable export laws and regulations, including without limitation the US Export Administration Regulations and the Foreign Exchange and Foreign Trade Act.
- 13) This document, in part or in whole, may not be reprinted or reproduced without prior consent of ROHM.



Thank you for your accessing to ROHM product informations.
More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

<http://www.rohm.com/contact/>

General Precaution

1. Before you use our Products, you are requested to carefully read this document and fully understand its contents. ROHM shall not be in any way responsible or liable for failure, malfunction or accident arising from the use of any ROHM's Products against warning, caution or note contained in this document.
2. All information contained in this document is current as of the issuing date and subject to change without any prior notice. Before purchasing or using ROHM's Products, please confirm the latest information with a ROHM sales representative.
3. The information contained in this document is provided on an "as is" basis and ROHM does not warrant that all information contained in this document is accurate and/or error-free. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties resulting from inaccuracy or errors of or concerning such information.